2. Conductors, Dielectrics & capacitances Electric diade :st is defined as and opposite charges and two equal charges and seperated by a small distance in called as electric dipole. Electric dipole morlement: - (m) the product of charge and distance. [m= axid] invector tor m= Qd then cont Expression for potential due to Electric dipole: r par 82 from the figure let it be required to determine the potential at point p" due to electric dépole with distance Of ri and v2 and r from positive charge, negative charge and centre. WKT The Jotential at any point is V= ar ar >CV

1

Now up is the potential at Applitude change

$$u_{12} = \frac{0}{4\pi\epsilon_{12}} \longrightarrow 12^{2}.$$
Us is the potential at -ve change

$$u_{22} = \frac{-0}{4\pi\epsilon_{12}} \longrightarrow (3)$$
Total fotential u_{12} with u_{12} at foint "p" is

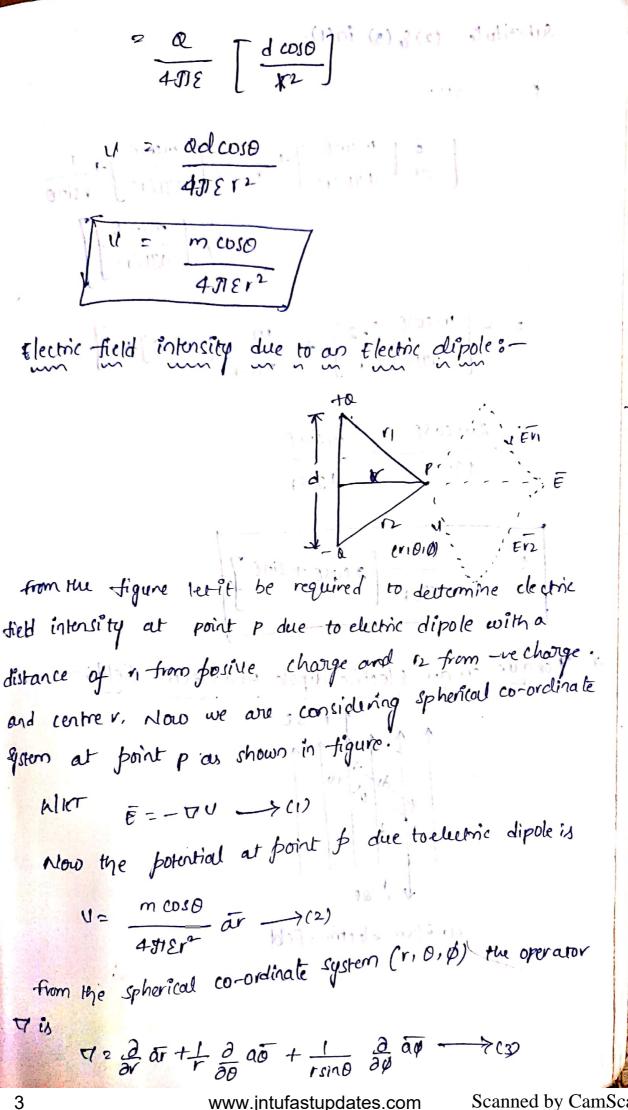
$$u = \frac{0}{4\pi\epsilon_{12}} - \frac{0}{4\pi\epsilon_{12}}$$

$$\frac{-0}{4\pi\epsilon_{12}} = \frac{-0}{4\pi\epsilon_{12}} \longrightarrow (4)$$
If the required point is foreaway to dipole morement
theo $r_{12} = r - \frac{d}{2} \cos 0$, $r_{22} = r + \frac{d}{2} \cos 0$
Aubstituting these values in eqn (4).

$$v_{2} = \frac{0}{4\pi\epsilon_{12}} \left[\frac{r}{r-\frac{d}{2}} \cos 0 - \frac{1}{r+\frac{d}{2}} \cos 0 \right]$$

$$= \frac{0}{4\pi\epsilon_{12}} \left[\frac{r}{r-\frac{d}{2}} \cos 0 + \frac{r}{r+\frac{d}{2}} \cos 0 - \frac{r}{r+\frac{d}{2}} - \frac{r}{r+\frac{d}{2}} \cos 0 - \frac{r}{r+\frac{d}{2}} - \frac{r}{r+\frac{d}{2}} \cos 0 - \frac{r}{r+\frac{d}{2}} - \frac{r}{r+\frac{d}{2}} - \frac{r}{r+\frac{d}{2}} - \frac{r}{r+\frac{d}{2}} - \frac{r}{r+\frac{d}{2}} -$$

2



Substitute (2) & (3) in(1).

$$\overline{E} = - \forall V$$

$$= - \left[\frac{\partial}{\partial r} \left[\frac{m \cos \theta}{4 \Im r} \right] + \frac{1}{r} \frac{\partial}{\partial \theta} \left[\frac{m \cos \theta}{[i \Im \Im r} \right] + \frac{1}{r \sin \theta} \right]$$

$$= - \left[\frac{m \cos \theta}{u \Im r} \left[\frac{2}{r^3} \right] + \frac{m}{4 \Im r} \left[-\sin \theta \right] + \frac{1}{r} \right]$$

$$= - \left[\frac{m \cos \theta}{u \Im r} \left[\frac{2}{r^3} \right] + \frac{m \sin \theta}{4 \Im r} \left[-\sin \theta \right] + \frac{1}{r} \right]$$

$$= \frac{2m \cos \theta}{4 \Im r} + \frac{m \sin \theta}{4 \Im r} \frac{1}{r^3}$$

$$= \frac{2m \cos \theta}{4 \Im r} + \frac{m \sin \theta}{4 \Im r} \frac{1}{r^3}$$

$$= \frac{1}{r} \left[2 \cos \theta + \sin \theta \right] \frac{1}{r^3}$$

$$= \frac{1}{r^3} \left[2 \cos \theta + \sin \theta \right] \frac{1}{r^3}$$

$$= \frac{1}{r^3} \left[2 \cos \theta + \sin \theta \right] \frac{1}{r^3}$$

$$= \frac{1}{r^3} \left[2 \cos \theta + \sin \theta \right] \frac{1}{r^3}$$

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$$= \frac{1}{r^3} \left[2 \cos \theta + \sin \theta \right] \frac{1}{r^3}$$

$$= \frac{1}{r^3} \left[\frac{1}{r^3} \left[\frac{1}{r^3} \right] \frac{1}{r^3} \left[\frac{1}{r^3} \left[\frac{1}{r^3} \right] \frac{1}{r^3} \left[\frac{1}{r^3} \left[\frac{1}{r^3} \right] \frac{1}{r^3} \left[\frac{1}{r^3} \left[\frac{1}{r^3} \left[\frac{1}{r^3} \right] \frac{1}{r^3} \right] \frac{1}{r^3} \left[\frac{1}{r^3} \left[\frac{1}{r^3} \left[\frac{1}{r^3} \right] \frac{1}{r^3} \left[\frac{1}{r^3} \left[\frac{1}{r^3} \left[\frac{1}{r^3} \right] \frac{1}{r^3} \left[\frac{1}{r^$$

consider an electric dipole is placed in uniform electric ifield it experience a force whose magnitude is equal and opposite to each other whe know that the torque is defined as.

M= Fxd = force x perpendiculor distance

WKT

 $F = \frac{\& | \& 0_2}{4 \pi E r^2}$ [columb's daw]

- $f \in \frac{Q_1}{4JIEr^2} \cdot Q_2$
 - $F = \overline{F} \cdot Q \rightarrow (2)$

substitute (27 inci)

Y= E·Rd

from the figure sino: $\frac{d}{d_1}$ d = disin0.

n= E. O. disino

₩ : Em sino

O=q8, sind=1

m2EM FINEDE EN I MITH TT = Exm [Lucctor form]

ma electric dépole movement c-m En well intensity = N/m (or) V/m www.jntufastupdates.com

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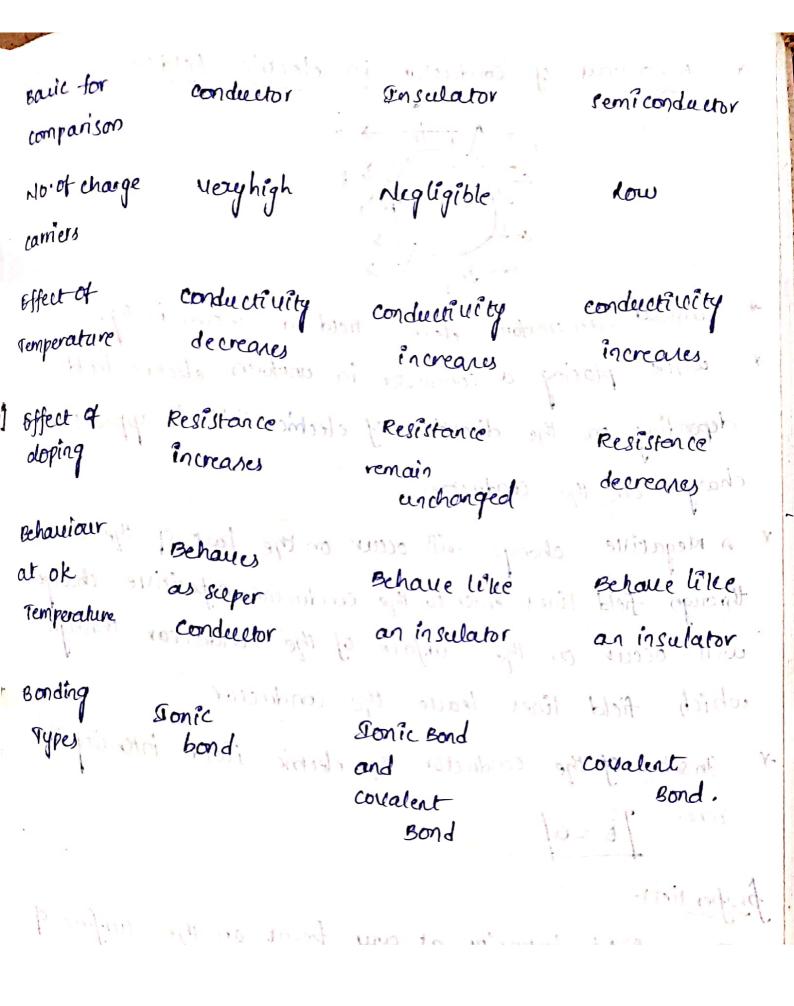
+
$$\Phi$$
 point change of $3\mu c$ and $-3\mu c$, are located at
 $loioni)$ and $loioi-1$ miss respectively in free space.
1) find electric dipole movement:
ii) find electric field intensity with sphurical co-ordinates $lo_{iil,s}$
iii) find Sintensity at point of $(1,2,1-5)$
 S^{0}_{1} : 0_{1} : $3\mu c$, 0_{2} : $-3\mu c$
 11 : $(0,011) + V_{2,c} (0,01-1)$
 $d = \sqrt{0+0+2^{-2}} = 2$
i) me Qxd
 $= 3\chi_{10}\delta_{\chi_{2}}$
 $> 6\chi_{10}\delta_{\chi_{3}}$ [$2\cos\theta + \sin\theta$]
 $= \frac{6\chi_{10}\delta_{\chi_{3}}}{4\pi \pi \chi_{3}}$ [$2\cos\theta + \sin\theta$]
 $= c6\pi 43.85 [1.532 + 0.642]$
 $E = \frac{m}{4\pi \epsilon_{3}}$ [$2\cos\theta + \sin\theta$]
 $E = \frac{m}{4\pi \epsilon_{3}}$ [$2\cos\theta + \sin\theta$]
 $E = \frac{m}{4\pi \epsilon_{3}}$ [$2\cos\theta + \sin\theta$]
 $= l\phi_{6}(41, 243)$
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I find the potential at print
$$P(10,66,6)$$
 due to dipole
theorge $e_1 : (\mu c at (0.1,0,0))$ and $e_2 = -[\mu c at (-0.1,0,0))$
is $e_1^{-1} = (1,10)^{-1} =$

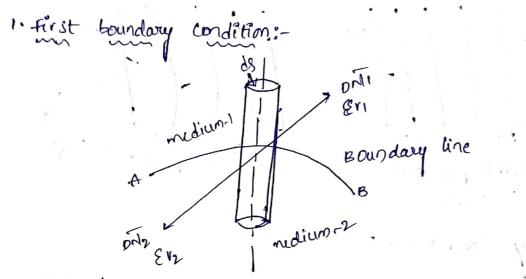
+ Differe	nce bla condu	ictor, insulat	or and semiconductors
· ····	n I att - [Pic	n lugar (11)	
Basic for	conductor	Inscilat	for semiconductor
comparison	10.015	0 · · · (°	Brith Carlo
Definition	The elements which allow the flow of electric curres through it by the application	which dor allow and flow of electric charge	not conductivity lies between insulatory and conductors
Electric conductivity	Voltage Good conductor	Back	At ok works, it works on an insulator. by adding impurity
F . 1	2 - 05 66 - 1 500 0	1	becomes good conductor
Examples	copper,	wood	Germanium,
	Merceory	Rubber	apir silicon
Energy bord	conduction band and Valarce bard overlap cach other	both are seperated by adjister bev	and realence band seperated by lev.
charge camers	electrons	they do not contain any charge camers	Intrinsic charge 1 Carriers are holes 1 and electrons
current	current flow	current does	
flow	due to		Cervert due to
	chebrons	not-flow	holes and cluston



Behaviour of conductor in electric field:-ENE opende la Stin prost 1=0 " consider an uniform electric field as shown in tig. * while placing a conductor in unitorm electric tield depending on the direction of electric field it appears 2 13(131)14 charges on the conductor. * A regative charge will occur on the fast of the conductor through field lines enter to the conductor of positive charge will occur on the surface of the conductor through which field lines leave the conductor. * Inside of the conductor the electric field intensity is Covalent tero. /Ē =0/ 6.003 properties)-- The field intensity at any point on the surface of the conductor is directly proportional to YEO times of Electric flux density D=EE E= ED

, Electricity field intensity inside of the conductor is the conductor surface is equal to * potential surface. 200. qui potential surface: -If all the points on the surface having the some potential then the scenface is called equipotential surface. and here was not been -1: 01-11 24 54 50 54 54 unequal potential surface, 54 54 54 Equal potential Surface Baindary Condition's:when an electric field passes from one medium to other medium it is important to study the conditions at the boundary between the 2-nedia. The conditions ent the boundary of z-midia when field passes existing trons one medium to another medium, that is called va t mota : à Conclition's. as boundary depending upon the nature of the media there are 2 situation's of the boundary conditions 11

- Boundary b/s adiclectrics.
- Boundary bin dielectric and conductor.
- " Boundary between two dielectrics ?-Grenerally the boundary between two diedectric consists of two parts.
 - 1. First boundary condition
 - 2. second boundary condition



The electric field intensity (Ē) and electric fear density (D) is required to be decomposed into two components namely tangential to the boundary, normal component to the boundary (Ē tan, Ēri, Dītan, Dīr)

E= Eton + EN

5 = Dtan + DN

* The first boundary condition deals with that into tod the normal component of electric flur density it. Date * from the fingure a, B in the boundary line bla medium-1 and neclian 2 with a relative permittivity of Er, Erz. 12 www.jntufastupdates.com Scanned by CamScanner

, now consider a small area d' on the boundary anung with a Guarian Serface. * 01, 02 are the angles. Acc. to Gauss dow J. D. des Qzy -> (1) from the figure, the electric flux leading the top and bottom surfaces (M-1, N1-2), 5 = 26 - 31 dsone - dsonle = a dsconi- onizica + 1+ 3 1 106.1 DNI-DN2= da da [da = Ss] poloniet in 10 . DAI-DN2-SS DN1 - DN2 20 (50001 3 - 1000 3] 100 The lines of DNIE DNJ2/GNOT 7 - INOT 3 at the boundary the surface charge density in 0. The romal component of electric fluir density is continous across the boundary bln two dielectrics. At in contrabul at access

ii) Gecond boundary condition:

$$\int \overline{E} \tan \int \frac{1}{4} \int \overline{E} - \pi \operatorname{tradium} - 1$$

$$\int \overline{E} \tan \frac{1}{4} \int \overline{E} - \pi \operatorname{tradium} - 2$$

$$\int \overline{E} \tan \frac{1}{4} \int \overline{E} - \pi \operatorname{tradium} - 2$$

$$\int \overline{E} - dE = 0$$

$$\int \overline{E} - dE = 0$$

$$\int \overline{E} - dE = 0$$

$$\int \overline{E} - dE + \int \overline{E} - dE + \int \overline{E} - dE + \int \overline{E} - dE = 0$$

$$\int \frac{1}{4} \int \overline{E} - dE + \int \overline{E} - dE + \int \overline{E} - dE + \int \overline{E} - dE = 0$$

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$$\int \frac{1}{4} \int \overline{E} - dE + \int \overline{E} - dE + \int \overline{E} - dE + \int \overline{E} - dE = 0$$

$$\int \overline{E} \tan (1 - \overline{E} \tan 2) = 0$$

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$$\int \overline{E} \tan (1 - \overline{E} \tan 2) = 0$$

14

Boundary between dielectric and conductor:-. M. liaportición en Electric field in a conductor in tero. Medium-1 E) B conductor: Medium-2 EQ Ē=0 Etane = Etana = 0 - - i findle plate advance an $\overline{E}_{T_1} = \overline{E}_{T_2}$ is each of conducting war copacitore and capacitor:capacitor: - scapacitor essentially consists of a conducting surfaces seperated by a small distance with dielectric medium. in called a capacitor. Generally the conducting surfaces are in the tom of Parallel plates, sphenical, rectongular, co-anial shapes. apacitance: - It is the property of capacitor and it stores the energy in the form of electric field. The capacitonce of the capacitor is defined as the charge per unit potential difference across its plates. 0 8 .01 $\therefore C = \frac{Q}{V} - farads$ 1. 1. 8 . 8

* Capacitonce of a parallel flate Capacitor.

$$\begin{array}{c}
\stackrel{\text{if}}{\longrightarrow} & \stackrel{\text{$$

substitute curin (5)

1 contaction of a provided 1 433 = 20 often y capacitance of a parallel plate capacitor with 2- Dielectric Media:-- 22 the principal copietor 2 Colorbate Pres Kdi * da -> the fig. constists of space 6/2 2-parallel plates tilled with a 2-oil-electric Media with a relative permitturity is we to it potential as any first in an elis of En . Enz. $kl\cdot k\cdot T$ $\overline{D} = \underbrace{Q} \longrightarrow UJ$ den i possibilité wikit the relation 5/2 5 and E is - the potential of a finner Surface 333 = Cetar a about to $\overline{E} = \frac{D}{E} \longrightarrow (a)$ (a) $\overline{D} = \frac{D}{E} \longrightarrow (a)$ $\overline{E_1} = \frac{\overline{O}}{\overline{EOEr_1}}$, $\overline{E_2} = \frac{\overline{O}}{\overline{EOEr_2}}$, \overline{OIII} The powerful of a autor surgare or BEETED & due to Us Eld1+ E2 d2 i o pour sition specto . 111 $U_{2} = \frac{\overline{D}}{\overline{\epsilon}} \left[\frac{dI}{\overline{\epsilon}r_{1}} + \frac{da}{\overline{\epsilon}r_{2}} \right] d$ given $\frac{d}{c} = \frac{d}{A \varepsilon_0} \left[\frac{d}{\varepsilon r_1} + \frac{d}{\varepsilon r_2} \right] \frac{d}{\varepsilon r_1} = \frac{d}{\varepsilon r_2} = \frac{d}{\varepsilon r_1}$ $C = \frac{A E_0}{\frac{d1}{sr_1} + \frac{d2}{sr_2}}$

17

+ capacitonce of a spherical plate capacitor:-Er - briner surface theor spherical conacitor consists of 2 concentratic spheres of radius a land b mt separated by a di-electric media Er pasitishows in tige die sitere inder potential at any foint is an electric field with - wekit r mt. i.e., $V = \frac{R}{45TEF}$ (1) due a distance of r mt. the potential of a inner surface conductor a duck to charge to ie., $(2)^{--1}$ $u_{\alpha} = \frac{0}{u_{TI} \epsilon \alpha} - \frac{1}{2} (2)$ The potential of a outer surface conductor & due to charge positive charge o is it. Vb-- - Q 4JTE b ->(3) with the total jotential win waters . $i = U_{2} = \frac{\alpha}{4\pi\epsilon}$

18

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$$\frac{\alpha}{4\pi\epsilon} \left[\frac{1}{a} - \frac{1}{b} \right]$$

$$\frac{\alpha}{4\pi\epsilon} \left[\frac{b-\alpha}{ab} \right]$$

$$\epsilon = \frac{\alpha}{4\pi\epsilon} \left[\frac{b-\alpha}{ab} \right]$$

$$\epsilon = \frac{\alpha}{4\pi\epsilon} \left[\frac{b-\alpha}{ab} \right]$$

$$\frac{\alpha}{4\pi\epsilon} \left[\frac{b-\alpha}{ab} \right]$$

$$\frac{\alpha}{4\pi\epsilon} \left[\frac{b-\alpha}{ab} \right]$$

$$\frac{\alpha}{4\pi\epsilon} \left[\frac{ab}{b-\alpha} \right]$$

-we keit the electric field intensity due to the charge

$$\overline{E} = \frac{SL}{2DEr} \longrightarrow U$$

$$= we keit the polential difference is$$

$$= \frac{SL}{2U} \xrightarrow{\int V} \overline{E} \cdot d\overline{I} \longrightarrow (2)$$

$$= \frac{SL}{2UE} \quad d\overline{I}$$

$$= \frac{SL}{2DEr} \quad d\overline{I}$$

$$= \frac{SL}{2DEr} \quad d\overline{I}$$

$$= \frac{SL}{2DEr} \quad d\overline{I}$$

$$= \frac{SL}{2DEr} \quad [Uog i]_{a}^{b}$$

$$= \frac{SL}{2DE} \quad [Uog i]_{a}^{b}$$

$$= \frac{SL}{2DE} \quad [Uog i]_{a}^{b}$$

1.

WHET
$$(2.6/U)$$

$$= \frac{\sqrt{3}}{3L} [log(b|a]]$$

$$= \frac{\sqrt{3}}{3L} [log(b|a]]$$

$$= \frac{\sqrt{3}}{2} [log(b|a]]$$

0

*C

$$= \frac{1}{c} \int_{0}^{0} \theta \cdot d\theta$$

$$= \frac{1}{c} \left[\frac{\theta^{2}}{2} \right]_{0}^{0}$$

$$= \frac{\theta^{2}}{2c}$$

$$w = \frac{1}{c} \cdot \theta \cdot \frac{\theta}{2}$$

$$= \frac{U \cdot \theta}{2c}$$

$$w = \frac{1}{c} \cdot \theta \cdot \frac{\theta}{2}$$

$$= \frac{U \cdot \theta}{2c}$$

$$w = \frac{1}{c} \cdot \theta \cdot \frac{\theta}{2}$$

$$= \frac{U \cdot \theta}{2c}$$

$$\frac{1}{2} \left[\frac{1}{2} - \frac{1}{c} \frac{U^{2}}{2} \right] J$$

$$= \frac{1}{c} \frac{1}{c} \frac{U^{2}}{2} \int J$$

$$= \frac{1}{c} \frac{1}{c} \frac{U^{2}}{2} \int J$$

$$= \frac{1}{c} \frac{1}{c} \frac{1}{c} \frac{U^{2}}{c} \int J$$

$$= \frac{1}{c} \frac{1}{c}$$

$$wd = \frac{1}{2} \mathcal{E} \frac{u^{2}}{d^{2}}$$

$$wz \in dE$$

$$E = \frac{u}{d}$$

$$wd = \frac{1}{2} \mathcal{E} (\overline{E})^{2}$$

$$wd = \frac{1}{2} \mathcal{E} (\overline{E})^{2}$$

$$wd = \frac{1}{2} \mathcal{E} (\overline{E})^{2}$$

$$\frac{wd}{2} = \frac{1}{2} (\overline{E})^{2}$$

$$\frac{wz}{2} = \frac{1}{2} (\overline{E})^{2}$$

$$\frac{wz}{2} = \frac{1}{2} (\overline{E})^{2}$$

$$\frac{wz}{2} = \frac{1}{2} (\overline{E})^{2}$$

$$\frac{wz}{2} = \frac{1}{2} (\overline{E})^{2}$$

N calculate capacitonce of a parallel plate capacitor
with following details.
Plate = 1000m²
diclectric
$$Er_1 = 4$$
.
 $dt = amm$
diclectric $Er_2 = 3$
 $d2 = 3mm$
H 200V is applied across the plates what will be the
Nothege gradient across each dielectrics and also find
the energy stored in a each dielectrics.
sd = $\frac{20}{C_1} = \frac{20}{C_2} = \frac{8\times25\times10^{-12} \times 100\times10^{-4}}{3}$
 $= \frac{385\times10^{-16}}{5\times16^{-4} + 1\times10^{-3}} = \frac{8\times25\times10^{-12} \times 100\times10^{-4}}{5\times16^{-4} + 1\times10^{-3}}$
 $= \frac{385\times10^{-16}}{5\times16^{-4} + 1\times10^{-3}} = \frac{50}{C_2} \times \frac{20}{C_2}$
 $= \frac{50}{C_1} \times \frac{20}{C_1} = \frac{20}{C_2} \times \frac{20}{C_2}$
 $= \frac{8\times85\times10^{-12} \times 100\times10^{-4}}{C_1} = \frac{8\times25\times10^{-12} \times 100\times10^{-4}}{C_2}$
 $= \frac{8\times85\times10^{-12}\times100\times10^{-4}}{C_1} = \frac{8\times85\times10^{-12}\times100\times10^{-4}}{C_2}$
 $= \frac{8\times85\times10^{-12}\times100\times10^{-4}}{C_2} = \frac{8\times85\times10^{-12}\times100\times10^{-4}}{C_2}$
 $= \frac{8\times85\times10^{-12}\times100\times10^{-4}}{C_2} = \frac{8\times85\times10^{-12}\times10^{-4}}{C_2}$
 $= \frac{8\times85\times10^{-12}\times10^{-5}}{C_2} = \frac{8\times10^{-12}\times10^{-5}}{C_2}$
 $= \frac{8\times85\times10^{-12}\times10^{-5}}{C_2} = \frac{8\times10^{-4}\times10^{-5}}{C_2}$
 $= \frac{8\times10^{-5}\times10^{-4}\times10^{-5}}{C_2} = \frac{8\times10^{-5}\times10^{-5}}{C_2}$

.

$$c \ge 9[u]$$

$$c \ge 9[u]$$

$$c \ge 9[a = 0$$

$$a \le 59 \times 10^{-12} \times a = 0$$

$$c \ge 59 \times 10^{-12} \times a = 0$$

$$c \ge 59 \times 10^{-12} \times a = 0$$

$$c \ge 59 \times 10^{-12} \times 1$$

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A aspherical condenser has capacitance 54 Pf it consists of
a concentratic spheres difference in radius by 2 cm having
and air has dielectric if radial of inner and acter sphere.

$$ai^{2}$$
 c: 54 Pf = 50 x 10¹² c
 $b - az 4 cm c 4 x 10^{2} m$
 $c = 4712 \begin{bmatrix} ab \\ b-a \end{bmatrix}$
 $54 \times 10^{-12} c = 4712 \begin{bmatrix} ab \\ b-a \end{bmatrix}$
 $54 \times 10^{-12} c = 4712 \begin{bmatrix} ab \\ b-a \end{bmatrix}$
 $ab: teaper 0.0194$
 $(atb)^{2} = (a-b)^{2} + 4ab$
 $= (-uxo)^{2} + 4x 1.942 \times 10^{2}$
 $ab = 16.0201$
 $b - a : 4x 10^{2}$
 $ab = 16.0201$
 $b - a : 4x 10^{2}$

* Convertie più she transfé comprise al songeli the flow of electrons (or) the charge flows from one place to phother place in the conductor. Rate of flow of charge is called as Current. It is denoted by I (0) i Any. tenter 1 Matthematically, $i = \frac{Q}{F}$ amont is a scalar quantity. s Current density: - The current density is defined as amont to unit surface prea. Mattumatically. $J = \frac{T}{A} (Applm^2)$ $J = \frac{dE}{dA}$, $J = \frac{dE}{dA}$, J =opende peloties Juda in Edazids] autobare a have i i dz : J. ds poi a contrat a in in and as $I = \int J \cdot ds / i =$ 1. 11 & VG

A Différence bla conduction aument density and			
Convection Current density:-			
$ \begin{array}{c} \downarrow \\ \downarrow $			
Convenction :-			
A set of charge particles giving raine to a charge			
density in a volume (R1) to have adrift velocity			
(vd) as shown in tig.			
the charge particles are assumed to maintain the			
irrelative positions with in the volumer as this charge			
configuration produces a surface (s). it is called as			
Convenction Current density (Jcon].			
Jeon & Ud			
Jcon = Jud			
Tcon: conventional current density min/m2			
S= Resistivity			
uds drift velocity.			
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conduction current density:-これらいためられた conduction current density ocured in the presence of electric field intensity associated with conductor with a-fixed cross-sectional area as shown in fig. It is indicated by Jc. mp/m2. makes in Aquer · Mathematically, elation tracky. Jeaud N 1 20 Jc = Jud WICT UddE 111 1 20 UdsHE JC2 HEP]]c== E | where -= conductivity = 1/p Jez conduction Current density E= Electric field intensity .: The above equation in called - as point form of ohm's daw" "point form of ohm's daws !-)+ Je>=(

Statement :-According to ohm's haw "At constant temperature the voltage across the two ends of the conductor is directly proportional to the current flowing through the conductor.

ar nhows is figure.

willit

Strates and All All A Mathena Hacly, idu =) Uzir i=U/R wkit RallA => Ra SI/A I = V Il (A 9 2 VA NPR printing $=\frac{1}{A}=\frac{1}{PL}$

=> J== E This is called as foint form of ohm's down

& Note

convenction (Icon) y convenction current occurs in insulators or dielectrics such as liquid, reaccurs gas etc.

conduction (Jc)

in conductor where there are konge no of free electron.

* convenction current does not involve conductors hence, it does not satisfy the Ohm's daw.

It satisfies ohm's how.

* Equation of continuity con Maxwell's fifth Equation. mu differential equation relating to current density (7) and where change density (sur at each point in the circuit in knows as Equation of continuity con continuity exuation,

= band on haw of conservation of theory, $I_c = -\frac{9}{t} - \frac{1}{t} - \frac{1}{$

 $w \cdot b \cdot \overline{\Gamma} \cdot \overline{J} = \frac{J}{s} \implies \overline{J} \cdot \frac{dF}{ds}$ $d\overline{I} = \overline{J} \cdot ds$ $S = \int \overline{J} \cdot ds \longrightarrow S$

W.E.T Ju= Q/V

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Q = Jourdu -> (2) substitute (2) & (3) in (1) Juds: -d (Judu) Applying divergence theorem fringdu = -d (fruidu) CI.J= -d (IW) TI TO + the (IV) =0 an province an